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## Atomically Well-defined Nitrogen Doping in the Cross-plane Transport through Graphene Heterojunctions

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The nitrogen doping of graphene leads to graphene heterojunctions with a tunable bandgap, suitable for electronics, electrochemical, and sensing applications. However, the microscopic nature and charge transport properties of atomic-level nitrogen-doped graphene are still unknown, mainly due to the multiple doping sites with topological diversities. In this work, we fabricated the atomically well-defined N-doped graphene heterojunctions and investigated the cross-plane transport through these heterojunctions to reveal the effects of doping on their electronic properties. We found that different doping number of nitrogen atoms leads to a conductance difference of up to ~288%, and the conductance of graphene heterojunctions with nitrogen-doping at different positions in the conjugated framework can also lead to a conductance difference of ~170%. Combined ultraviolet photoelectron spectroscopy measurements and theoretical calculations reveal that the insertion of nitrogen atoms into the conjugation framework significantly stabilizes the frontier molecular orbitals, leading to a change in the relative positions of HOMO and LUMO to the Fermi level of the electrodes. Our work provides a unique insight into the role of nitrogen doping on the charge transport through graphene heterojunctions and materials at the single atomic level.

## Introduction,

The two-dimensional (2D) heterostructured materials not only retain the original advantages[1, 2] but also show unique charge transport[3-5], catalytic activity[6], mechanical strength[7], photoelectric property[8], and magnetic properties[9] beyond the classic two-dimensional materials. For instance, the doping of graphene leads to the fabrication of graphene heterojunctions with potential applications in electronics[10-14], sensing[15, 16], photocatalytic[17-19] and other aspects by converting the zero bandgaps of graphene to tunable bandgaps[20]. Nitrogen is widely used for doping graphene materials and devices[15, 19, 21, 22], and there are various nitrogen-doping approaches developed, including chemical vapor deposition[23], arc discharge[24], ion irradiation[25] and post treatment[26]. However, the microscopic nature and charge transport properties of atomic-level nitrogen-doped graphene remained unclear due to the complexity of the

nitrogen sites and bonding topology within the carbon lattice during the doping process[20, 25, 27, 28]. Along this line, recent advances in the investigation through single-molecule junctions offer a unique insight to reveal the role of N-doping with atomically well-defined doping sites.

To tackle this challenge, the single-molecule junctions with gold-molecule-gold configurations offer the opportunity to investigate the role of N-doping in the charge transport through molecular junctions with atomic precision. When nitrogen doping occurs in the aromatic cores of molecules, differences in the substitution positions can tune the quantum interference effects[29-31] and demonstrate the different gating efficiency[32] in a phenyl ring with *meta* connectivity. When nitrogen atoms are employed as an anchor group to form Au-N bonds[33, 34], the different numbers and sites of nitrogen atoms provide different conductance pathways at molecular junctions, resulting in different conductance[35, 36]. However, all the above studies investigated the charge transport through the molecular skeleton using gold electrodes but not the cross-plane transport as presented in the graphene heterojunctions. Recent advances in the fabrication of cross-plane heterojunctions can be considered as a microscopic model[37] to investigate the role of nitrogen doping on the charge transport with different numbers of nitrogen atoms at different positions of the conjugated framework in nitrogen-containing polycyclic aromatic hydrocarbons (N-PAHs).

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Chemical Science Accepted Manuscript

**ARTICLE**

Herein, we investigated the charge transport through nitrogen-doped graphene heterojunctions where N-PAHs are embedded between graphene electrodes by using the cross-plane break junction technique and density functional theory transport calculations. Comparing the conductance values of the corresponding polycyclic aromatic hydrocarbons (PAHs), we find that the conductance decreases with the introduction of nitrogen atoms. We further investigated the conductance of heterojunctions with nitrogen atoms at different N-PAH framework sites and observed a clear site dependence in their conductance. In conjunction with transition voltage spectroscopy (TVS), ultraviolet photoelectron spectroscopy (UPS), and theoretical calculations, it is supposed that the insertion of nitrogen atoms alters the energy level alignment between the frontier molecular orbitals and the Fermi level of graphene electrodes, thereby regulating the electrical properties.
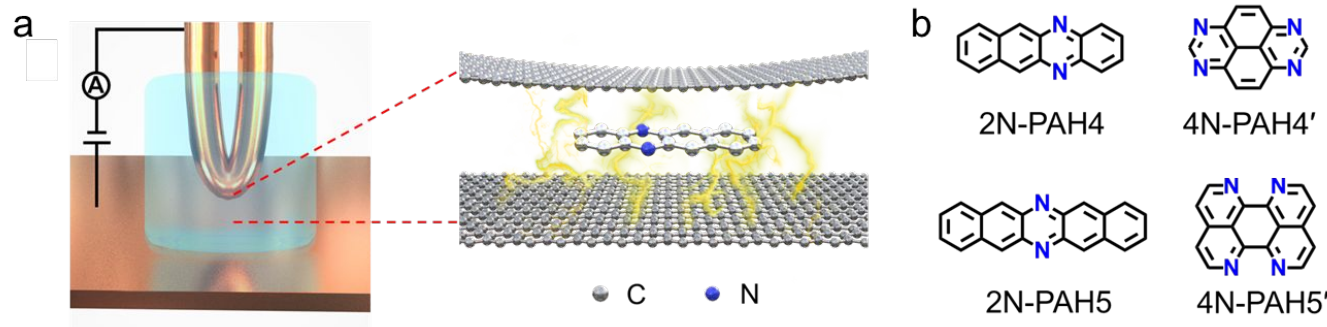


**Fig. 1** Schematic diagrams and molecular structures. (a) Schematic diagrams of the cross-plane break junction (XPBJ) setup based on STM-BJ setup (left) and the structures of sandwiched molecular junctions with a N-PAH (right). (b) Chemical structures of N-PAHs, including 5,12-diazatetracene (2N-PAH4), 1,3,6,8-tetraazapyrene (4N-PAH4'), 6,13-diazapentacene (2N-PAH5), 1,6,7,12-tetraazaperylene (4N-PAH5').

## Results and discussion

We investigate the cross-plane charge transport through the N-PAHs using the customized scanning tunneling microscopy break junction (STM-BJ) setup as shown in Fig. 1a left and Fig. S1 in the Supporting Information (SI). A U-shaped Cu wire with single-layer graphene and a Cu foil with single-layer graphene is chosen as substrates, and the tip is in soft contact with the substrate using with the lab-developed control program[38-40]. A push-pull process of the tip forms nanoscale gaps of varying sizes, and the molecule can be trapped in the nanogap between the graphene electrode pair and form a graphene-molecule-graphene van der Waals (vdW) heterojunction. The charge transport occurs in a cross-plane way due to the vdW interaction (Fig. 1a right). We have synthesized four N-PAH molecules as probe molecules[41-45], whose structures are shown in Fig. 1b.

The conductance of the graphene-based single-molecule junctions with a bias voltage of 0.1 V ranged from $10^{-6.5}$ $G_0$ (~24.5 pS; $G_0=2e^2/h$, quantum conductance) to $10^{-2.5}$ $G_0$ (~245.4 nS) at room temperature. Direct tunneling traces were obtained in pure decane as a solvent and showed neither a discernible peak in the one-dimensional (1D) conductance histogram nor a plateau in the 2D conductance histogram. Typical individual conductance–displacement traces are shown in Fig. 2a in the inset. For all four molecules, there are distinct conductance plateaus ranging from $10^{-5}$ $G_0$ (~775 pS) to $10^{-4}$ $G_0$ (~7.75 nS); over 1000 individual conductance–distance traces are overlayed for statistical analysis. Distinct peaks were observed in the 1D conductance histogram (Fig. 2a), indicating that the molecular junctions of four N-PAHs were successfully constructed. The conductance of 2N-PAH4 and 4N-PAH4' are $10^{-4.81}$ $G_0$ (~1.20 nS) and $10^{-4.69}$ $G_0$ (~1.58 nS) by Gaussian fitting of the peaks, respectively. Interestingly, 2N-PAH5 and 4N-PAH5' have conductance of $10^{-4.41}$ $G_0$ (~3.02 nS) and $10^{-4.28}$ $G_0$ (~4.07 nS), respectively, which are much higher than those of the former two counterparts. The relationship between the conductance and the structures of the molecules is shown in Fig. 2b, and the conductance of N-PAHs increase with the number of benzene rings, which is consistent with the conductance of PAHs[38]. The cross-plane area is an essential factor affecting the conductance. The conductance of 2N-PAH5 decreases most significantly, falling down to 46.8% of that of PAH5 ($10^{-4.08}$ $G_0$, 6.45 nS[38]), whereas the conductance of 4N-PAH4' increases most manifestly up to 135% of that of PAH4' ($10^{-4.82}$ $G_0$, 1.17 nS[38]), which is about ~288% of the former decrease. Compared to their PAH counterparts[38], both 2N-PAH4 and 2N-PAH5 show a decrease in conductance by 63.1% and 46.8%, respectively, indicating that the former decrease is about ~135% of the latter one. With the increase of the number of nitrogen atoms to four, the conductance of 4N-PAH5' slightly decreases by 79.4%, while that of 4N-PAH4' actually increases by 135%, which is about ~170% of the former decrease (see Table S1 in the SI). Such a bipolar change can be accounted for by the fact that the insertion of nitrogen atoms stabilizes both the highest occupied molecular orbital (HOMO) and the lowest unoccupied molecular orbital (LUMO), leading to a change in the relative positions of HOMO and LUMO to the Fermi level of the electrodes. For a detailed explanation, see the section on the theoretical calculations.

The 2D conductance-distance histograms of N-PAHs are constructed by superimposing conductance-displacement traces to investigate the junction configurations. As shown

in Fig. 2c, there are corresponding apparent intensity clouds in the range of conductance demonstrated in the 1D conductance histogram, indicating the successful construction of graphene-molecule-graphene junctions. Based on the plateau length of direct tunneling at 0.27 nm determined in pure solvent[38, 39, 46], the corrected plateau lengths of 2N-PAH4, 2N-PAH5, 4N-PAH4', and 4N-PAH5' are determined to be 0.96 nm, 0.92 nm, 0.90 nm, and 0.93 nm, respectively (Fig. 2d). They match the distance between the graphene sheet incorporated with N-PAHs, meaning the sandwiched graphene-N-PAHs-graphene junctions are successfully fabricated. Although the direct gold-aromatic rings junctions were reported[47], we tried to use gold

electrodes to investigate the conductance of PAHs. Due to the absence of anchoring group and weak van der Waals interaction at room temperature[48], PAHs which are planar molecules do not show the obvious conductance signal in the one-dimensional conductance-displacement histogram when gold electrodes are used (see Fig. S13 in the SI). On the contrary, N-PAHs form molecular junctions through N-Au coordination bonds (see Fig. S12 in the SI). In remarkable contrast to graphene-molecule-graphene van der Waals heterojunctions, Au-N-PAHs-Au junctions do not seem to be able to accurately assess the influence of nitrogen atoms on charge transport through PAHs due to N-Au coordination bonds.
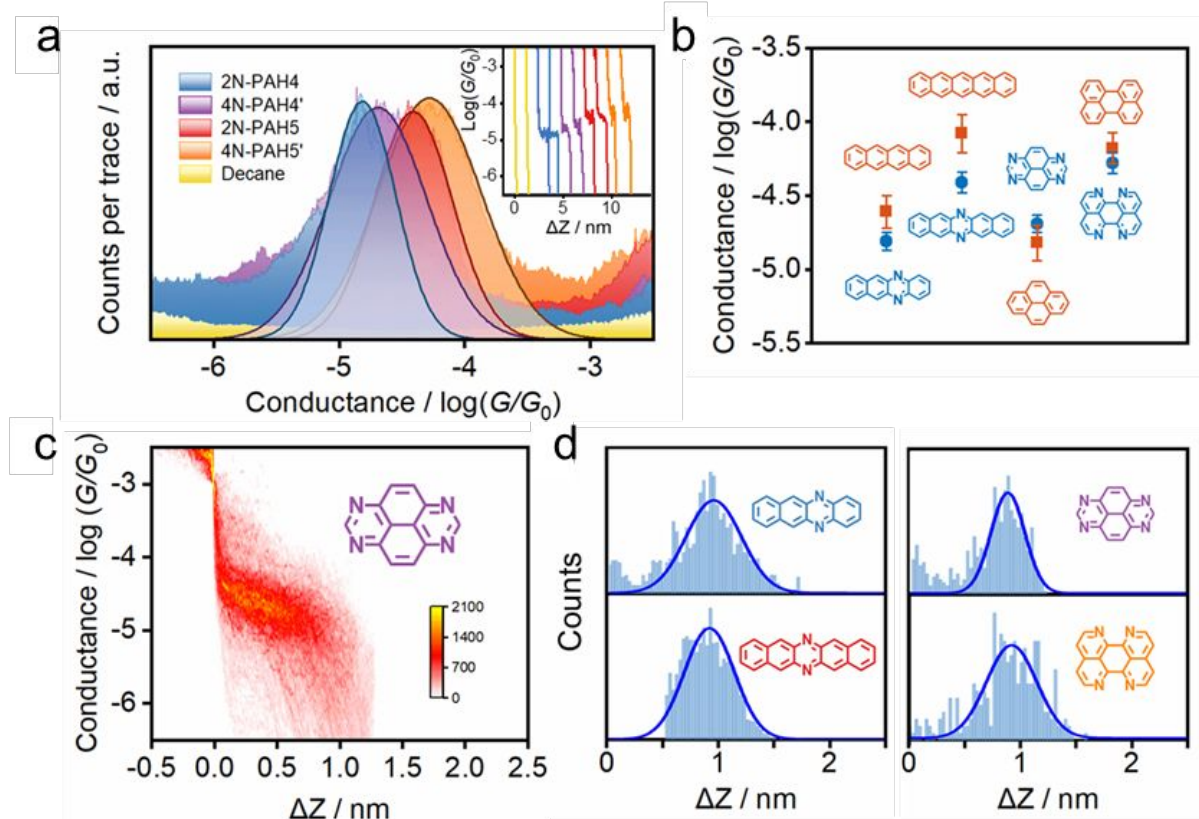


**Fig. 2** Electrical properties with XPBJ technique. (a) 1D conductance histograms were obtained from ~1000 conductance–displacement traces of the pure decane solvent (yellow) and the N-PAHs using graphene electrodes. The typical individual conductance–displacement traces are shown in the inset. (b) Comparison of conductance between N-PAHs and PAHs. The data of PAH conductance comes from our previous work. [38] (c) 2D conductance-distance histograms of 4N-PAH4'. (d) The plateau length histograms of 2N-PAH4, 2N-PAH5, 4N-PAH4', and 4N-PAH5'.

To further investigate the change of HOMO and LUMO energy levels, UPS and ultraviolet-visible (UV-Vis) spectra were used to evaluate the energy level alignment of these junctions. UPS measurements were performed using a He Ⅰ light source ($h\nu$ = 21.22 eV) to gauge the electronic states of monolayers on graphene[49]. At an applied bias of -5 V, all the binding energy spectra are shown in Fig. S6 in the SI. We find that the insertion of nitrogen atoms gives rise to an increase in the energy offset ($E_F - E_{HOMO}$) as predicted by DFT calculations (Fig. 3a). The ultraviolet-visible (UV-Vis) spectra show that the HOMO-LUMO gaps of N-PAHs also decrease or remain almost unchanged

compared to their PAH counterparts (see Fig. S7 in the SI). From the UPS and UV-Vis results, it can be deduced that the LUMO energy levels of N-PAHs decrease more rapidly than the HOMO energy levels, and notably, 4N-PAH4' shows the most pronounced drop in the LUMO energy.

To further determine energy level alignment in the heterojunctions, we measured TVS to obtain the transition voltage ($V_{trans}$). After the $I$-$V$ measurements of all molecules, Fowler-Nordheim diagrams (describing the relationship between $\ln(I/V^2)$ and $1/V$) were obtained using a specific mathematical analysis method called TVS. Two trends corresponding to two

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different charge-transport mechanisms can be seen in the plots. The boundary between these two trends, the minimum value in the F-N plot, is defined as the transition voltage. The value of $V_{trans}$ is proportional to the energy offset between the Fermi energy ($E_F$) of the electrodes and the energy of the frontier molecular orbital ($E_{FMO}$, HOMO or LUMO)[50-52]. The $V_{trans}$ values of N-PAHs and PAHs are linear with the absolute values of the theoretical $E_F$-$E_{FMO}$ (Fig. 3b). At the same time, the $V_{trans}$ values of N-PAHs and PAHs are compared (Fig. 3c). The $V_{trans}$ values of 2N-PAH5 and PAH5 are 0.396 V and 0.289 V, and the $V_{trans}$ values of 2N-PAH4 and PAH4 are 0.463 V and 0.342 V, suggesting that $V_{trans}$ increases after the insertion of nitrogen atoms. The results show that the $E_F$-$E_{HOMO}$ increases and $E_{HOMO}$ decreases due to the presence of nitrogen atoms, which is consistent with the theoretical calculations. In stark contrast, the frontier molecular orbital shifts from HOMO to LUMO when the number of nitrogen atoms is increased to four. The $V_{trans}$ values of 4N-PAH5' and PAH5' are 0.423 V and 0.369 V, respectively. And the $V_{trans}$ value of 4N-PAH4' (0.423V) is slightly smaller than that of PAH4' (0.463 V), indicative of a significantly reduced LUMO. This observation is corroborated by the UPS results mentioned earlier. It follows that 4N-PAH4' and 4N-PAH5' show a LUMO-dominated charge-transport mechanism that is distinct from the HOMO-dominated charge-transport through other N-PAHs and their PAH counterparts. It becomes clear that an interplay between the number of nitrogen atoms and the topology variation is applied to fine-tune the energy levels between the frontier orbitals and the Fermi level of the graphene electrodes, thereby regulating the charge-transport properties of the PAHs.
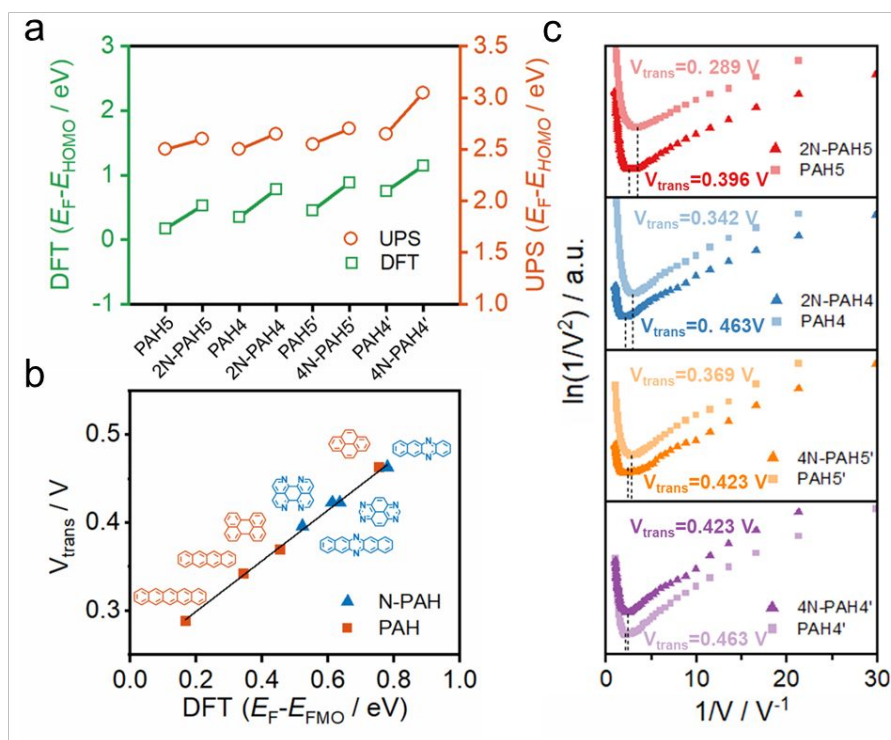
**Fig. 3** Ultraviolet photoelectron spectroscopy and transition voltage spectroscopy. (a) Comparison of $E_F - E_{HOMO}$ by UPS with $E_F - E_{FMO}$ by DFT theoretical calculation. (b) $V_{trans}$ versus $E_F - E_{FMO}$ by DFT theoretical calculation difference. (c) The transition voltage ($\ln(I/V^2)$ vs $1/V$) spectra were obtained by over 500 $I$–$V$ traces of 2N-PAH5, PAH5, 2N-PAH4, PAH4, 4N-PAH5', PAH5', 4N-PAH4', PAH4'.

To understand the charge-transport properties of N-PAH and PAH molecules between graphene electrodes (Fig. 4a), we calculated the ground-state geometries and electronic structures of gas phase molecules using SIESTA[53] implementation of density functional theory (DFT) firstly as discussed in the method section in the SI. We find that HOMO and LUMO energy levels for each molecule move down in energy with the insertion of nitrogen atoms (see Table S4 in the SI). Next, we calculated ground-state geometries and electronic structures of molecules between two graphene electrodes (see methods). The calculated average optimum distance between the graphene sheet and molecules is between 3.42 to 3.46 Å depending on the type of N-PAHs and PAHs molecules (see Table S5 in the SI). The smallest vdW distance (3.42 Å) is for 4N-PAH4'. The graphene electrodes are periodic in the $y$ and $x$ directions with multiple $k$-points (Fig. 4a) to resemble graphene sheets. We found that the ground state distance between graphene sheets is 3.36 Å in the transport direction ($z$).

To calculate cross-plane conductance through graphene-based single-molecule junctions, we obtain the mean-field Hamiltonian from density functional theory (DFT) and use the Gollum[54, 55] quantum transport code (see theoretical methods) to calculate transmission coefficients of electrons of energy $E$ passing from one electrode to the other. We then used the Landauer formula

to calculate the electrical conductance (see theoretical methods). Since the molecules can interact with graphene electrodes in different stacking configurations, three different structures of AB, AA and a mixture of AA and AB stacking are considered. Fig. 4b-e show the calculated ensemble average conductance of 3 different configurations (from AB to AA stacking) of N-PAHs and PAHs molecules between graphene electrodes with multiple $k$-points (5×5) perpendicular to the transport direction.

Fig. 4e shows the calculated average conductance of PAH4' (red line) and 4N-PAH4' (blue line) as a function of the Fermi energy $E_F$. The HOMO resonance for 4N-PAH4' has shifted to the left far away from the Fermi energy by ~0.39 eV, while the LUMO resonance has shifted to the left by ~1.23 eV and is closer to $E_F$. This large shift of the LUMO resonance toward $E_F$ combined with its slightly smaller vdW distance increases the electrical conductance. The black dashed line at $E_F$ = -0.18 eV in Fig. 4b-e shows the Fermi energy that gives the best agreement with experiments for all molecules (see Fig. S9 in the SI), and several previous zero bias calculations have shown good agreement with such measurements.[56-59] The LUMO resonances of 2N-PAH4 and 2N-PAH5 are also shifted downward in energy, as depicted in Fig. 4c, b, but not as much as for 4N-PAH4'. Consequently, the

electrical conductance values of 2N-PAHs are lower than those of the corresponding PAHs at $E_F$ (-0.18 eV). As shown in Fig. 4d, the same holds true for 4N-PAH5' (blue line), which has a lower conductance than PAH5'. We also performed calculations with a different graphene electrode configuration, as shown in Fig. S10, S11 in the SI, and found similar results. As shown in Fig. 4f, we obtain the positions of HOMO (red circles) and LUMO (green circles) resonances relative to the Fermi energy of electrodes for each molecular junction from Fig. 4b-d. Our calculation shows that in N-PAHs molecules, HOMO and LUMO energy levels move downward in energy, and the shift of LUMO energy level is larger for molecules with a higher number of nitrogen atoms, such as 4N-PAH4' and 4N-PAH5'. The largest shift of the LUMO energy happens to be in 4N-PAH4'. It is worth mentioning that electron transport in PAHs occurs close to HOMO, in agreement with the previous reports[38]. However, electron transport in N-PAHs happens to move from HOMO to LUMO because the molecular orbitals move downward in energy and the FMOs change due to the higher number of nitrogen atoms. Our calculations also indicate that the conductance order between different PAHs and N-PAHs is sensitive to the choice of $E_F$, so gating by a third electrode could lead to different orders.
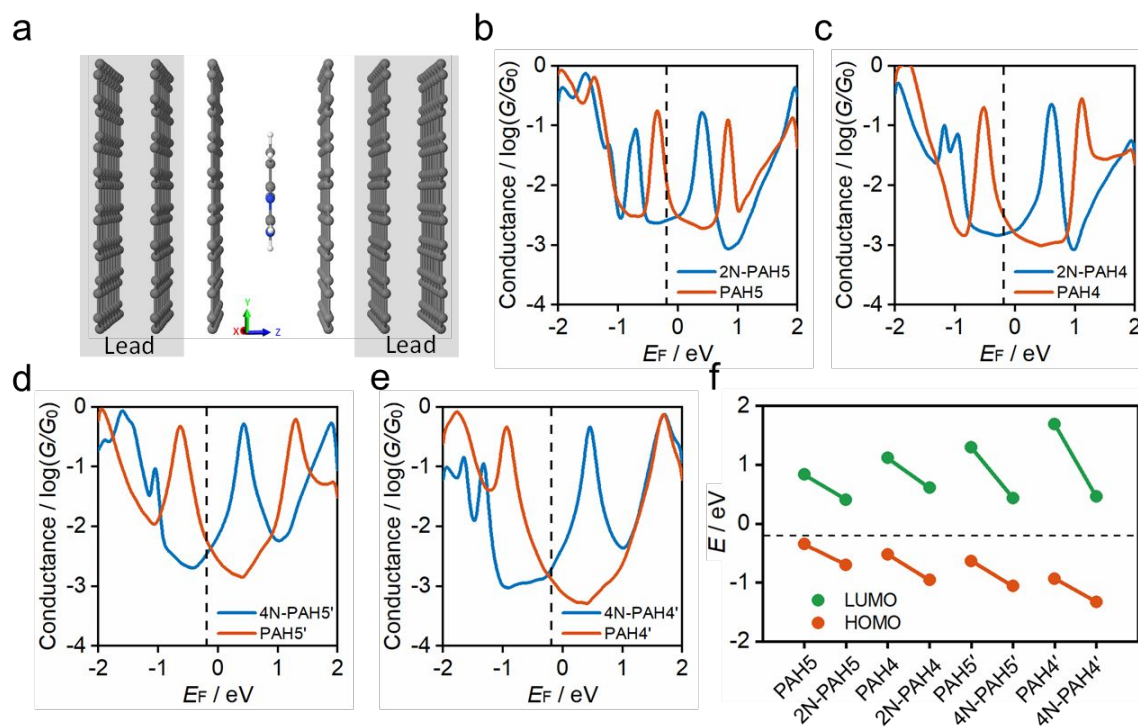


**Fig. 4** Electrical conductance properties of graphene-molecule-graphene van der Waals heterojunctions. (a) Structure of sandwiched molecular junctions with a 4N-PAH4' molecule. (b-e) The electrical conductance of N-PAHs and PAHs molecules as a function of Fermi energy. The black dashed line ($E_F$ = -0.18 eV) shows the Fermi energy that agrees with the experiment results. (f) Energetic position of HOMO and LUMO resonances of graphene-molecule-graphene junctions obtained from Fig. b-e. The black dashed line shows $E_F$ = -0.18 eV.

## Conclusions

In summary, we fabricated the atomically well-defined N-doped graphene heterojunctions and investigated the cross-plane transport through these heterojunctions to reveal the

effect of doping on their electronic properties. We found that the electronic cloud distribution via vdW interactions between N-PAHs and graphene electrodes plays an essential role in their conductance, and the presence of nitrogen atoms has a pronounced effect on the alignment of the energy levels of HOMO and LUMO with respect to the Fermi level of the electrodes. Given a HOMO-dominated charge transport through PAHs and N-PAHs, the insertion of nitrogen atoms significantly stabilizes the HOMO, leading to a decrease in the conductance of N-PAH compared to that of its PAH counterpart. As the number of nitrogen atoms increases, the LUMO becomes more stabilized than the HOMO. Together with a variation in the topology and the number of the phenyl rings of N-PAHs, the LUMO-dominated charge transport occurs, leading to a slight decrease (4N-PAH5') and an increase (4N-PAH4') in the conductance of N-PAH compared with that of its PAH counterpart. Our work represented a solid step for the actual application of the graphene device via cross-plane transport and demonstrated the essential role of heteroatoms in two-dimensional heterojunctions.

## Methods

### Materials

The Cu wires and Cu foils with single-layer graphene were purchased from 6 Carbon Technology (Shenzhen, China). 2N-PAH4[44], 2N-PAH5[44], 4N-PAH4'[42, 45], and 4N-PAH5'[41, 43] were prepared according to literature procedures.

### Single-molecule conductance measurements

We used XPBJ technique modified from a home-built STM-BJ setup[60] to perform single-molecule conductance measurements. A 0.1 V bias voltage was applied at room temperature. See more details in Section S2, and the previous work[38].

### Transition voltage spectroscopy

Conductance measurements were performed with an applied bias of 0.1 V. When a conductance plateau appeared from $10^{-5}$ $G_0$ (~775 pS) to $10^{-4}$ $G_0$ (~7.75 nS), the movement of the piezo was paused and the tip was stationary. The bias voltage was scanned between -1 V and 1 V and the *I-V* curves were recorded during the process. More than 1000 curves were collected for statistical analysis. The fitting curve was obtained from the 2D *I-V* histogram, and the transition voltage spectrum was plotted based on the previous works[50-52].

### Ultraviolet photoelectron spectroscopy

UPS measurements were performed to estimate the electronic structure of N-PAHs and PAHs on graphene. The binding energy spectra were obtained using a He Ⅰ light source (hν = 21.22 eV) at an applied bias of -5 V. More details are included in S25.

### Theoretical Calculation

The optimized geometries with ground-state Hamiltonian and overlap matrix elements for gas phase molecules and molecules between graphene electrodes were obtained using density functional theory (DFT). These results were then combined with the Green function method to calculate the phase-coherent, elastic-scattering properties of the system, consisting of two graphene electrodes and the molecule as the scattering region. From the calculated transmission functions, the electrical conductance was calculated using the Landauer formula. See the Supporting Information for details of computational methods.

## Data availability

All data that support the findings of this study are available from the corresponding author upon reasonable request.

## Author Contributions

W. H., Y. Y., H. S., and S. L. co-supervised the project. H. Z., P. Z. and A. D. prepared the manuscript with input from all authors H. Z., S. Z., Z. Y., Y. Z. and Y. Z. carried out experiments and analyzed the data. P. Z., S. D. and R. H. synthesized molecules. A. D. and S. S. carried out theoretical calculations. All authors have approved the final version of the manuscript.

## Conflicts of interest

There are no conflicts to declare.

## Acknowledgements

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